Notice: You cannot copy or search for text in this PDF file, because this PDF file is converted from the scanned image of printed materials.

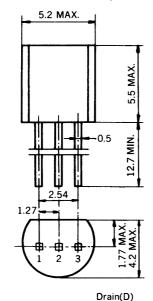
P1 98.2



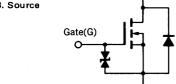
MOS FIELD EFFECT TRANSISTOR 2SK1484

N-CHANNEL MOS FET FOR SWITCHING

PACKAGE DIMENSIONS (Unit: mm)



- 1. Gate
- 2. Drain



(Diode in the figure is the parasitic diode.)

Source(S)

The 2SK1484, N-channel vertical type MOS FET, is a switching device which can be driven directly by the output of ICs having a 5 V power source.

As the MOS FET has low on-state resistance and excellent switching characteristics, it is suitable for driving actuators such as motors, relays, and solenoids.

FEATURES

- Directly driven by ICs having a 5 V power source.
- Has low on-state resistance $R_{DS(on)1} = 1.2 \Omega MAX$. @ $V_{GS} = 4.0 V$, $I_{D} = 0.5 A$ $R_{DS(on)2} = 0.8 \Omega MAX$. @ $V_{GS} = 10 V$, $I_{D} = 0.5 A$
- Can be used complementary with the 2SJ198

QUALITY GRADE

Standard

Please refer to "Quality grade on NEC Semiconductor Devices" (Document number IEI-1209) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

ABSOLUTE MAXIMUM RATINGS $(T_a = 25 \degree C)$

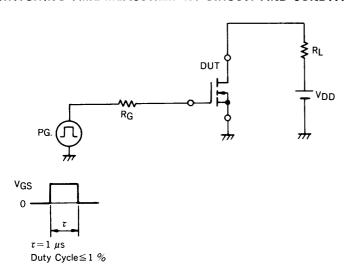
PARAMETER	SYMBOL	RATINGS	UNIT	TEST CONDITIONS	
Drain to Source Voltage	V _{DSS}	100	V	V _{GS} = 0	
Gate to Source Voltage	V _{GSS}	±20	V	V _{DS} = 0	
Drain Current	ID(DC)	±500	mA		
Drain Current	I _D (pulse)	±1.0	Α	PW ≦ 10 ms, Duty Cycle ≦ 50 %	
Total Power Dissipation	PT	750	mW		
Channel Temperature	T _{ch}	150	°c		
Storage Temperature	T _{stg}	-55 to +150	°C		

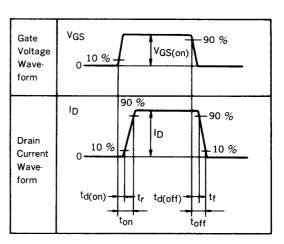


ELECTRICAL CHARACTERISTICS ($T_a = 25$ °C)

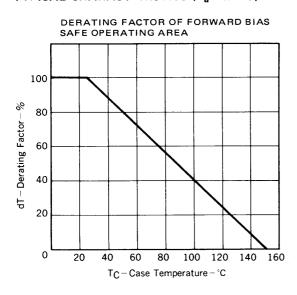
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS	
Drain Cut-off Current	IDSS			10	μΑ	V _{DS} = 100 V, V _{GS} = 0	
Gate Leakage Current	IGSS			±10	μΑ	V _{GS} = ±20 V, V _{DS} = 0	
Gate Cut-off Voltage	VGS(off)	0.8	1.2	2.0	V	V _{DS} = 10 V, I _D = 1 mA	
Forward Transfer Admittance	ly _{fs}	0.4			s	V _{DS} = 10 V, I _D = 0.5 A	
Drain to Source On-State Resistance	R _{DS(on)1}		0.6	1.2	Ω	V _{GS} = 4.0 V, I _D = 0.5 A	
Drain to Source On-State Resistance	R _{DS(on)2}		0.5	0.8	Ω	V _{GS} = 10 V, I _D = 0.5 A	
Input Capacitance	Ciss		230		рF	V _{DS} = 10 V, V _{GS} = 0, f = 1 MHz	
Output Capacitance	Coss		80		pF		
Feedback Capacitance	C _{rss}		12		pF		
Turn-On Delay Time	^t d(on)		14		ns	$V_{GS(on)}$ = 10 V, R_G = 10 Ω V_{DD} = 25 V, I_D = 0.5 A R_L = 50 Ω	
Rise Time	t _r		14		ns		
Turn-Off Delay Time	^t d(off)		370		ns		
Fall Time	t _f		65		ns		

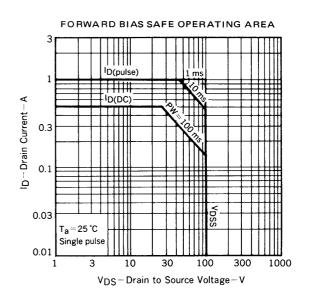
SWITCHING TIME MEASUREMENT CIRCUIT AND CONDITIONS

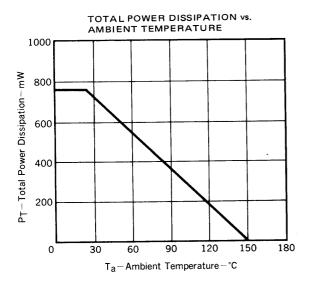


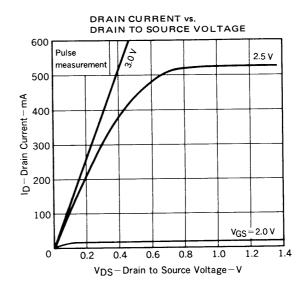


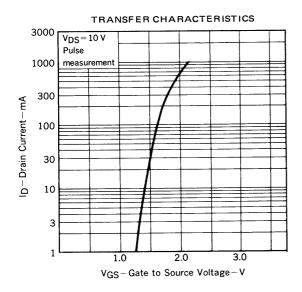
TYPICAL CHARACTERISTICS (T_a = 25 °C)

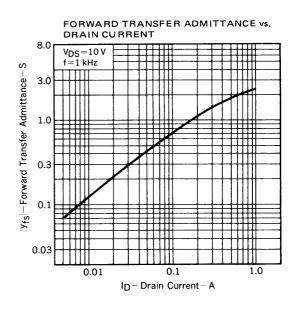


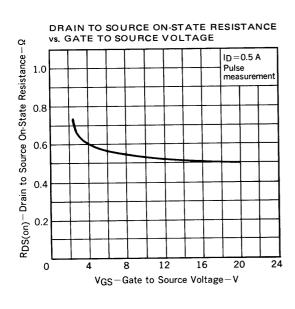


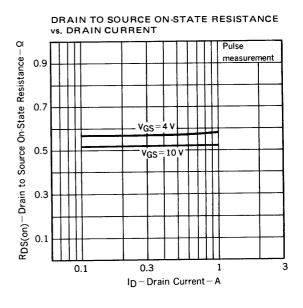


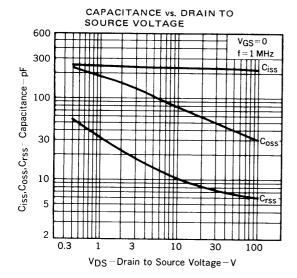


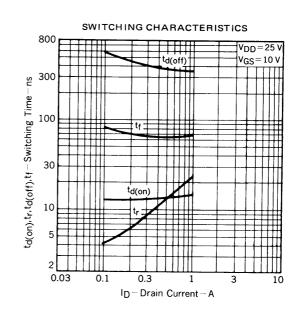


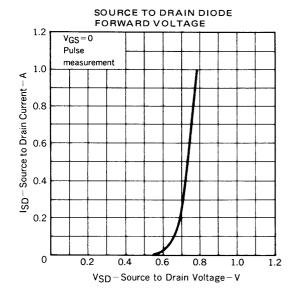












RECOMMENDED SOLDERING CONDITIONS

Solder this product under the following recommended conditions.

For soldering methods or soldering conditions other than those recommended in the table, please consult our NEC salespeople.

Insert type

Soldering method	Soldering conditions	Recommended condition code
Wave soldering	Solder bath temperature: 260 °C max. Soldering time: 10 sec max.	

5

(MEMO)

No part of this document may be copied or reproduced in any form or by any means without the prior written consent of NEC Corporation. NEC Corporation assumes no responsibility for any errors which may appear in this document.

NEC corporation does not assume any liability for infringement of patents, copyrights or other intellectual property rights of third parties by or arising from use of a device described herein or any other liability arising from use of such device. No license, either express, implied or otherwise, is granted under any patents, copyrights or other intellectual property rights of NEC Corporation or others.

The devices listed in this document are not suitable for use in the field where very high reliability is required including, but not limited to, aerospace equipment, submarine cables, unclear reactor control systems and life support systems. If customers intend to use NEC devices for above applications or those inted to use "Standard", or "Special" quality grade NEC devices for the applications not intended by NEC, please contact our sales people in advance.

Application examples recomended by NEC Corporation

Standard: Data processing and office equipment, Communication equipment (terminal, mobile). Test and

Measurement equipment, Audio and Video equipment, Other consumer products, etc.

Special: Automotive and Transportation equipment, Communication equipment (trunk line), Train and

Traffic control devices, industrial robots, Burning control systems, antidisaster systems, anticrime

systems etc.